U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE

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| INFORMATION DISCLOSURE STATEMENT | | Docket Number 10191/2262 | | |
|---|-------------------------|----------------------------------|------------------------|--|
| Application Number 0 / 07028 To Be Assigned | Filing Date Herewith | Examiner To Be Assigned | An Unit To Be Assigned | |
| Invention Title METHOD FOR PRODUCING A SEMICONDUCTOR COMPONENT AND A SEMICONDUCTOR COMPONENT PRODUCED ACCORDING TO THE METHOD | | Inventor(s) Hubert BENZEL et al. | | |

Assistant Commissioner for Patents Washington, D.C. 20231

- 1. In accordance with the duty of disclosure under 37 C.F.R. § 1.56 and in conformance with the procedures of 37 C.F.R. §§ 1.97 and 1.98 and M.P.E.P. § 609, attorneys for Applicants hereby bring the following references (cited in the specification of the above-identified application) to the attention of the Examiner. The references are listed on the attached modified PTO Form No. 1449. It is respectfully requested that the information be expressly considered during the prosecution of this application, and that the references be made of record therein and appear among the "References Cited" on any patent to issue therefrom.
- 2. A copy of each patent, publication or other information listed on the modified PTO form 1449 is enclosed, except as otherwise indicated on the modified PTO form 1449.

Dated: 3/5/02

By:

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JG19 Racia PCT/PTO 05 MAR 2002

| | Arty. Docket No. 10191/2262 | set 0/070286 To Be Assigned | |
|---|-----------------------------------|--------------------------------|--|
| INFORMATION DISCLOSURE STATEMENT BY APPLICANT | Applicate(s) Hubert BENZEL et al. | | |
| PTO FORM 1449 | Filing Date Herewith | Group T Be Assigned | |

U. S. PATENT DOCUMENTS

| EXAMINER'S INITIALS | PATENT NUMBER | PATENT DATE | NAME | CLASS | SUBCLASS | FILING DATE |
|------------------------|------------------|----------------|---------------|-------|----------|----------------|
| | 5,725,785 | March 10, 1998 | Ishida et al. | | | |

^{*}Copy of reference is not enclosed because reference is cited in Search Report (copy of reference provided by International Searching Authority).

FOREIGN PATENT DOCUMENTS

| | | | | • |] | TRANS | LATION |
|------------------------|--------------------|----------------|---------|-------|-----------|-------|--------|
| EXAMINER'S INITIALS | DOCUMENT NUMBER | DATE | COUNTRY | CLASS | SUB-CLASS | YES | NO |
| | WO 98/53351 | Nov. 26, 1998 | PCT | | | | |
| | 1 079 431 | Feb. 28, 2001 | EP | | | | |
| | 0 867 921°. | Sept. 30, 1998 | EP | | [] | | |

^{*}Copy of reference is not enclosed because reference is cited in Search Report (copy of reference provided by International Searching Authority).

OTHER DOCUMENTS

| EXAMINER'S INITIALS | AUTHOR, TITLE, DATE, PERTINENT PAGES, ETC. |
|------------------------|---|
| | Rinke et al., "Quasi-Monocrystalline Silicon for Thin-Film Devices," Applied Physics A: Materials Science and Processing, Springer Verlag, Berlin, Federal Republic of Germany (June 1999)" |

^{*}Copy of reference is not enclosed because reference is cited in Search Report (copy of reference provided by International Searching Authority).

| EXAMINER | DATE CONSIDERED | | | | |
|---|-----------------|--|--|--|--|
| EXAMINER: Initial if citation considered, whether or not citation is in conformance with M.P.E.P. 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. | | | | | |